

IRFB4610 Information

Part Number IRFB4610

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 100V 73A TO-220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

For Reference Only Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRFB4610 Specifications

Manufacturer Part Number	IRFB4610
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	73A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 100μA
Gate Charge (Qg) (Max) @ Vgs	140nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3550pF @ 50V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	190W (Tc)
Rds On (Max) @ Id, Vgs	14 mOhm @ 44A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IRFB4610 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFB4610 Payment Methods



















IRFB4610 Shipping Methods













If you have any question about IRFB4610, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com